# **Dual Bias Resistor Transistors**

# **NPN Silicon Surface Mount Transistors** with Monolithic Bias Resistor Network

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SOT-553 package which is designed for low power surface mount applications.

#### **Features**

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- Moisture Sensitivity Level: 1
- Available in 8 mm, 7 inch Tape and Reel
- Lead–Free Solder Plating
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50	Vdc
Collector-Emitter Voltage	V <sub>CEO</sub>	50	Vdc
Collector Current	Ι <sub>C</sub>	100	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	P <sub>D</sub>	230 (Note 1) 338 (Note 2) 1.8 (Note 1) 2.7 (Note 2)	mW °C/W
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	540 (Note 1) 370 (Note 2)	°C/W
Thermal Resistance – Junction-to-Lead	$R_{\theta JL}$	264 (Note 1) 287 (Note 2)	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-4 @ Minimum Pad

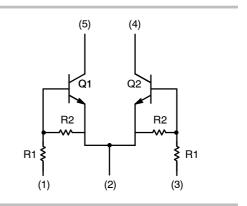
2. FR-4 @ 1.0 x 1.0 inch Pad



## **ON Semiconductor®**

http://onsemi.com

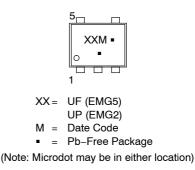
## NPN SILICON **BIAS RESISTOR** TRANSISTORS





SOT-553 CASE 463B





#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

#### **DEVICE MARKING AND RESISTOR VALUES**

Device	Package	Marking	R1 (K)	R2 (K)
EMG2DXV5	SOT-553	UP	47	47
EMG5DXV5	SOT-553	UF	10	47

#### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS (Q1 & Q2)					
Collector-Base Cutoff Current (V <sub>CB</sub> = 50 V, $I_E = 0$ )	I <sub>CBO</sub>	-	-	100	nAdc
Collector-Emitter Cutoff Current ( $V_{CE}$ = 50 V, $I_B$ = 0)	I <sub>CEO</sub>	-	-	500	nAdc
$ \begin{array}{ll} \mbox{Emitter-Base Cutoff Current (V_{EB}=6.0 V, I_{C}=0) \\ \mbox{EMG2DXV5} \\ \mbox{EMG5DXV5} \end{array} \end{array} $	I <sub>EBO</sub>			0.1 0.2	mAdc
Collector-Base Breakdown Voltage ( $I_C = 10 \ \mu A$ , $I_E = 0$ )	V <sub>(BR)CBO</sub>	50	-	-	Vdc
Collector-Emitter Breakdown Voltage (Note 3) $(I_{\rm C} = 2.0 \text{ mA}, I_{\rm B} = 0)$	V <sub>(BR)CEO</sub>	50	-	-	Vdc
ON CHARACTERISTICS (Q1 & Q2) (Note 3)		•		-	•
DC Current Gain ( $V_{CE}$ = 10 V, $I_C$ = 5.0 mA) EMG2DXV5 EMG5DXV5	h <sub>FE</sub>	80 80	140 140		
Collector-Emitter Saturation Voltage (IC = 10 mA, $I_B = 0.3$ mA)	V <sub>CE(sat)</sub>	-	-	0.25	Vdc
	V <sub>OL</sub>			0.2 0.2	Vdc
Output Voltage (off) (V_{CC} = 5.0 V, V_B = 0.5 V, R_L = 1.0 k $\Omega$ )	V <sub>OH</sub>	4.9	-	-	Vdc
Input Resistor EMG2DXV5 EMG5DXV5	R <sub>1</sub>	32.9 7.0	47 10	61.1 13	kΩ
Resistor Ratio EMG2DXV5 EMG5DXV5	R <sub>1</sub> /R <sub>2</sub>	0.8 0.17	1.0 0.21	1.2 0.25	

3. Pulse Test: Pulse Width < 300  $\mu$ s, Duty Cycle < 2.0%

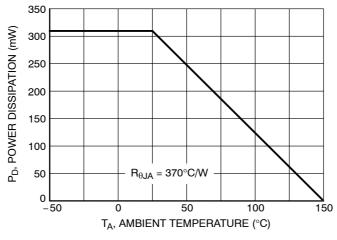


Figure 1. Derating Curve

## TYPICAL ELECTRICAL CHARACTERISTICS — EMG2DXV5

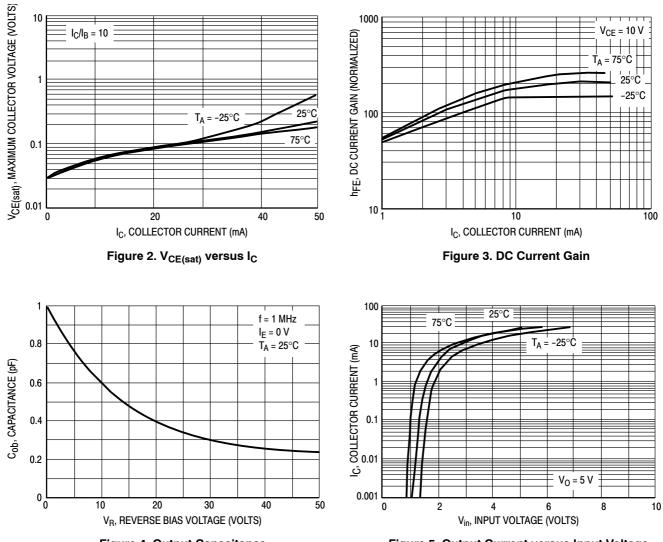


Figure 4. Output Capacitance

Figure 5. Output Current versus Input Voltage

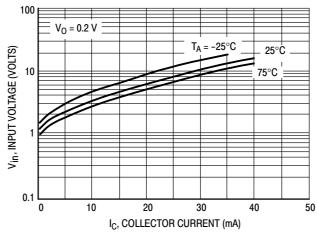
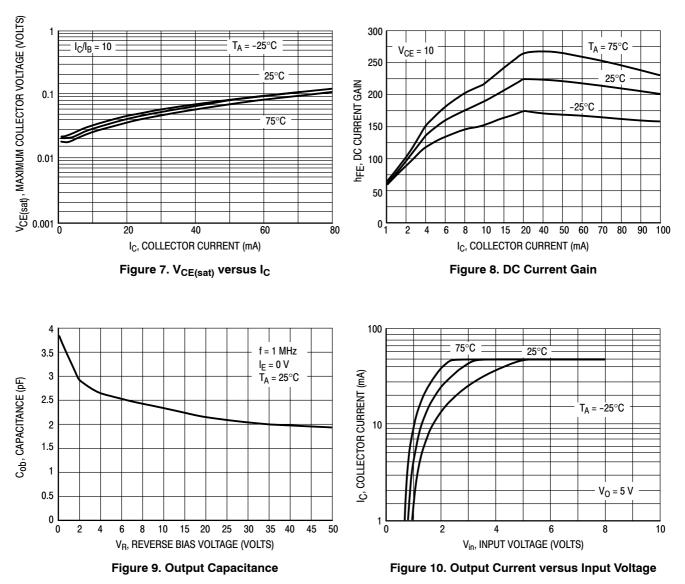


Figure 6. Input Voltage versus Output Current

### **TYPICAL ELECTRICAL CHARACTERISTICS – EMG5DXV5**



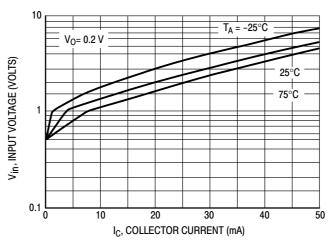


Figure 11. Input Voltage versus Output Current

## **TYPICAL APPLICATIONS FOR NPN BRTs**

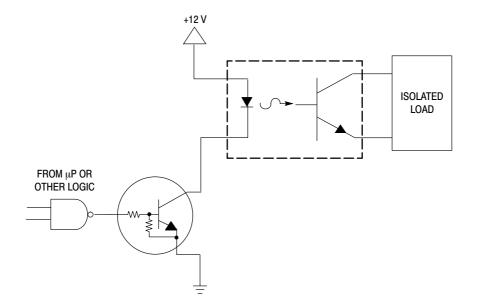


Figure 12. Level Shifter: Connects 12 or 24 Volt Circuits to Logic

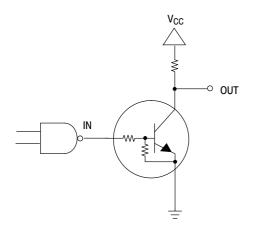
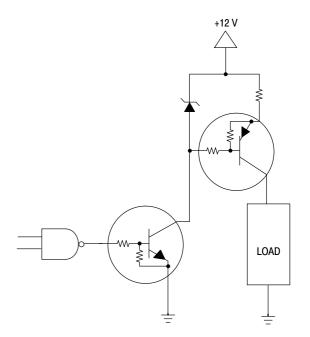


Figure 13. Open Collector Inverter: Inverts the Input Signal





#### **DEVICE ORDERING INFORMATION**

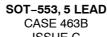
Device	Package	Shipping <sup>†</sup>
EMG2DXV5T1G	SOT-553 (Pb-Free)	4000 / Tape & Reel
EMG2DXV5T5G	SOT-553 (Pb-Free)	8000 / Tape & Reel
EMG5DXV5T1G	SOT-553 (Pb-Free)	4000 / Tape & Reel
EMG5DXV5T5G	SOT–553 (Pb–Free)	8000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

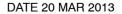


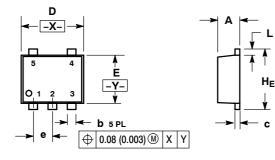


SCALE 4:1

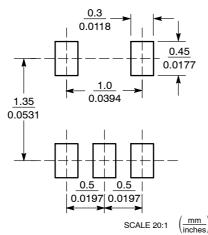


ISSUE C





#### RECOMMENDED **SOLDERING FOOTPRINT\***



NOTES

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2 3.

CONTROLLING DIMENSION: MILLIMETERS MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIMETERS		INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.50	0.55	0.60	0.020	0.022	0.024
b	0.17	0.22	0.27	0.007	0.009	0.011
С	0.08	0.13	0.18	0.003	0.005	0.007
D	1.55	1.60	1.65	0.061	0.063	0.065
Е	1.15	1.20	1.25	0.045	0.047	0.049
е	0.50 BSC			0.020 BSC	)	
Г	0.10	0.20	0.30	0.004	0.008	0.012
HE	1.55	1.60	1.65	0.061	0.063	0.065

## GENERIC **MARKING DIAGRAM\***

## XXM•

XX = Specific Device Code M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:
PIN 1. BASE	PIN 1. CATHODE	PIN 1. ANODE 1	PIN 1. SOURCE 1	PIN 1. ANODE
2. EMITTER	2. COMMON ANODE	2. N/C	2. DRAIN 1/2	2. EMITTER
3. BASE	3. CATHODE 2	3. ANODE 2	3. SOURCE 1	3. BASE
4. COLLECTOR	4. CATHODE 3	4. CATHODE 2	4. GATE 1	4. COLLECTOR
5. COLLECTOR	5. CATHODE 4	5. CATHODE 1	5. GATE 2	5. CATHODE
STYLE 6:	STYLE 7:	STYLE 8:	STYLE 9:	
PIN 1. EMITTER 2	PIN 1. BASE	PIN 1. CATHODE	PIN 1. ANODE	
2. BASE 2	2. EMITTER	2. COLLECTOR	2. CATHODE	
3. EMITTER 1	3. BASE	3. N/C	3. ANODE	
4. COLLECTOR 1	4. COLLECTOR	4. BASE	4. ANODE	
5. COLLECTOR 2/BASE 1	5. COLLECTOR	5. EMITTER	5. ANODE	

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ISSUE	REVISION	DATE
А	ADDED STYLES 3–9. REQ. BY D. BARLOW	11 NOV 2003
В	ADDED NOMINAL VALUES AND UPDATED GENERIC MARKING DIAGRAM. REQ. BY HONG XIAO	27 MAY 2005
С	UPDATED DIMENSIONS D, E, AND HE. REQ. BY J. LETTERMAN.	20 MAR 2013

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